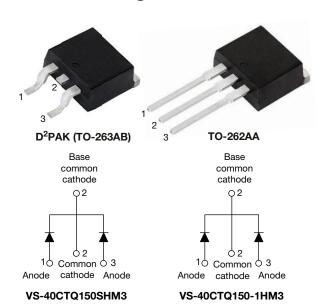
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COMPLIANT

HALOGEN

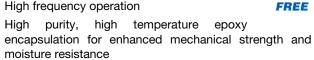
High Performance Schottky Rectifier, 2 x 20 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V_R	150 V					
V _F at I _F	0.71 V					
I _{RM}	15 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	1 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- Very low forward voltage drop
- 175 °C T_J operation
- Center tap TO-220 package
- High frequency operation



- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meet JESD 201 class 1 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	А			
V _{RRM}		150	V			
I _{FSM}	t _p = 5 µs sine	1500	Α			
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.71	V			
T _J		-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-40CTQ150SHM3 VS-40CTQ150-1HM3	UNITS			
Maximum DC reverse voltage	V _R	150	V			
Maximum working peak reverse voltage	V_{RWM}	130	V			



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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward per leg current, see fig. 5 per device		1	50 % duty ovalo at T ₋ = 140 %	rootangular wayoform	20			
		I _{F(AV)}	50 % duty cycle at T_C = 140 °C, rectangular waveform		40			
Market and a second and a			5 μs sine or 3 μs rect. pulse	Following any rated	1500	Α		
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	250			
Non-repetitive avalanche energy	Non-repetitive avalanche energy per leg		T _J = 25 °C, I _{AS} = 1.5 A, L = 0.9 mH		1.0	mJ		
Repetitive avalanche current per	r leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1.5	Α		

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		20 A	T ₁ = 25 °C	0.93			
Maximum forward voltage drop per leg See fig. 1	V (1)	40 A	1J=25 C	1.16	V		
	V _{FM} ⁽¹⁾	20 A	T _ 105 °C	0.71			
		40 A	T _J = 125 °C	0.85			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	50	μΑ		
See fig. 2		T _J = 125 °C	V _R = nateu V _R	15	mA		
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		450	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000					

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C			
Maximum thermal resistance, junction to case per leg	В	DC operation See fig. 4	1.5				
Maximum thermal resistance, junction to case per package	- R _{thJC}	DC operation	0.75	°C/W			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.5				
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Marking device		Case style D ² PAK (TO-263AB)	40CTQ	150SH			
ivial king device		Case style TO-262	40CTQ	150-1H			



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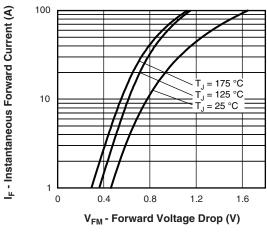


Fig. 1 - Maximum Forward Voltage Drop Characteristics

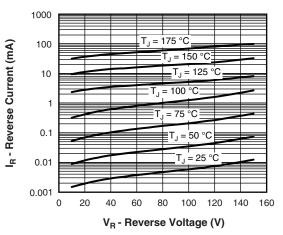


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

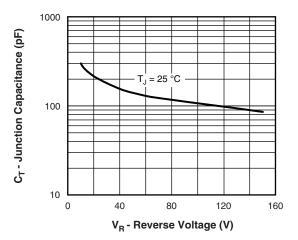


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

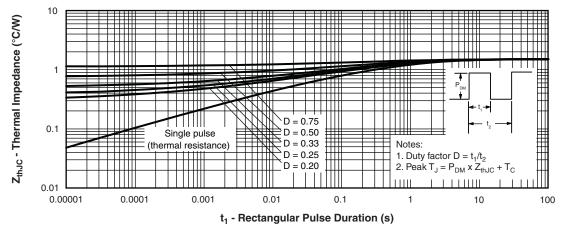


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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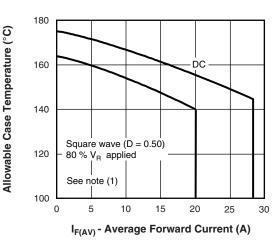


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

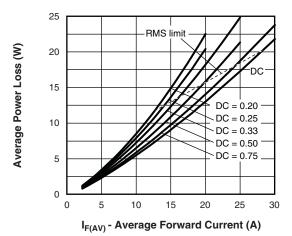


Fig. 6 - Forward Power Loss Characteristics

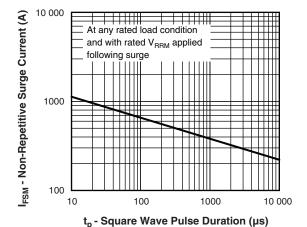


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

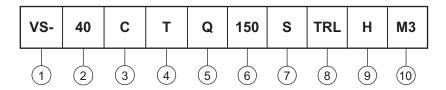
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % V_R applied

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 A)

- Circuit configuration:

C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (150 = 150 V)

7 - • S = D²PAK

• -1 = TO-262

None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

| 10 | - M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-40CTQ150SHM3	50	1000	Antistatic plastic tubes				
VS-40CTQ150STRLHM3	800	800	13" diameter reel				
VS-40CTQ150STRRHM3	800	800	13" diameter reel				
VS-40CTQ150-1HM3	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Dark manding information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?95032				
SPICE model		www.vishay.com/doc?95434				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		S	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164



Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches

Modified JEDEC® outline TO-262







⊕ 0.010 **M** A**M** B

Lead assignments



Diodes 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

	I		T		
SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
 (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- Controlling dimension: inches
- Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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